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United States Patent Application Publication

20250259848

Kind Code

A1

Publication Date

August 14, 2025

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DIVIDING METHOD OF WAFER

Abstract

A dividing method of a wafer includes cutting a front surface of the wafer to a predetermined depth with a cutting blade to form bottomed cut-grooves, applying a water-soluble liquid resin to the front surface of the wafer and drying the water-soluble liquid resin to fill the cut-grooves with the resulting dried water-soluble resin, grinding the wafer at the back surface thereof with grinding stones, so that the cut-grooves are allowed to appear in the back surface of the wafer and the wafer is divided into individual chips, and ejecting rinse water against the wafer, which has been divided into the chips, to remove the water-soluble resin.

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Family ID: 1000008492190

Appl. No.: 19/041343

Filed: January 30, 2025

Foreign Application Priority Data

| | | |
|----|-------------|---------------|
| JP | 2024-018165 | Feb. 08, 2024 |
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Publication Classification

Int. Cl.: H01L21/304 (20060101); H01L21/67 (20060101); H01L21/683 (20060101);
H01L21/78 (20060101)

U.S. Cl.:

CPC H01L21/3043 (20130101); H01L21/6715 (20130101); H01L21/6838 (20130101);
H01L21/78 (20130101);

Background/Summary

BACKGROUND OF THE INVENTION

Field of the Invention

[0001] The present invention relates to a dividing method of a wafer, which divides the wafer along a plurality of intersecting streets.

Description of the Related Art

[0002] In a fabrication process of semiconductor devices, for example, a disk-shaped semiconductor wafer (hereinafter simply called a “wafer”) is defined at a front surface thereof into a plurality of device regions along streets (scribe lines) formed in a lattice pattern, and devices such as integrated circuits (ICs) or large-scale integration (LSI) circuits are formed in the individual device regions, respectively. A plurality of device chips is obtained by dividing, along the streets, the wafer on which such many devices are formed. The chips divided as described above are packaged and extensively used in various kinds of electronic equipment such as personal computers and smartphones.

[0003] In recent years, there is a demand for downsizing and weight reduction of various kinds of electronic equipment, so that chips used in these electronic equipment tend to have a smaller thickness. Thinning of the chips is performed by grinding the wafer at a back surface therefore before the wafer is divided. If the thinned wafer is divided into the individual chips by dicing or the like, however, a problem arises in that chipping or the like is prone to occur on the chips.

[0004] As a wafer dividing method that resolves the above-described problem, a dividing technique called “Dicing Before Grinding” was developed, and has already found practical utility (see, for example, JP S64-038209 A). This dicing before grinding is a method that divides a wafer into individual chips by forming cut-grooves to a predetermined depth (a depth to such an extent as not to completely cut apart the wafer) from a front surface of the wafer before grinding the wafer at a back surface thereof, and with a protective sheet bonded on the front surface of the wafer, grinding the wafer at the back surface thereof to allow the cut-grooves to appear.

[0005] In the method that the wafer is divided into the individual chips by the above-described dicing before grinding, however, the grinding is continued until the chips have a desired thickness even after the cut-grooves have appeared in the back surface of the wafer. Accordingly, abrasive grits separated from grinding stones and grinding debris ground off from the wafer penetrate into the cut-grooves (gaps between the adjacent chips themselves), thereby raising a problem such as contamination of the chips at side surfaces thereof or induction of chipping, damage, or the like of the chips.

[0006] In JP 2001-176822A, filling of cut-grooves of a wafer with an interference prevention material such as a curable liquid resin is hence proposed. In JP 2009-224659A, a method is also proposed in which, after a solvent-free hydrophilic resin is applied in a liquid or viscoelastic form to a front surface of a wafer, where cut-grooves are formed, and is cured, the wafer is ground at a back surface thereof to divide the wafer into individual chips, and then the hydrophilic resin is brought into contact with warm water of 40° C. or higher to remove it from the individual chips.

SUMMARY OF THE INVENTION

[0007] However, the wafer dividing methods proposed in JP 2001-176822A and JP 2009-224659A have a problem in that time is needed for the removal of the curable liquid resin or the hydrophilic resin and productivity is poor accordingly.

[0008] The present invention therefore has as an object thereof the provision of a method of dividing a wafer, which can improve the productivity by removing a resin, which covers cut-grooves of the wafer, in a short time.

[0009] In accordance with an aspect of the present invention, there is provided a method of

dividing a wafer, which is defined at a front surface thereof into a plurality of regions by a plurality of intersecting streets and carries devices formed in the regions, respectively, along the streets to obtain a plurality of chips. The method includes holding the wafer on a first chuck table of a cutting machine with the front surface directed upward, cutting the front surface of the wafer to a predetermined depth along the streets with a cutting blade of the cutting machine to form bottomed cut-grooves, applying a water-soluble liquid resin from a side of the front surface of the wafer and drying the water-soluble liquid resin to fill the cut-grooves with the resulting dried water-soluble resin, bonding a protective sheet onto the front surface of the wafer, holding the wafer on a second chuck table of a grinding machine with a back surface thereof directed upward, grinding the wafer, which is held on the second chuck table, at the back surface thereof with grinding stones, so that the cut-grooves are allowed to appear in the back surface of the wafer and the wafer is divided into individual chips, and ejecting rinse water against the wafer, which has been divided into the chips, to remove the water-soluble resin filled in the cut-grooves.

[0010] According to the wafer dividing method of the present invention, a relatively small amount of a water-soluble resin layer filled in each cut-groove can be dissolved and removed in a short time. As a result, the productivity of the chips can be improved. In addition, as the cut-grooves are filled with the water-soluble resin layers in the cutting, sticking of cutting debris to side surfaces of the divided chips can be avoided.

[0011] The above and other objects, features and advantages of the present invention and the manner of realizing them will become more apparent, and the invention itself will best be understood from a study of the following description and appended claim with reference to the attached drawings depicting or illustrating a preferred embodiment of the invention.

Description

BRIEF DESCRIPTION OF THE DRAWINGS

[0012] FIG. 1 is a perspective view of a wafer;

[0013] FIG. 2 is a flow chart illustrating procedures of a wafer dividing method according to the present invention;

[0014] FIG. 3 is a side cross-sectional view depicting a first holding step in the wafer dividing method according to the present invention;

[0015] FIG. 4 is a side cross-sectional view depicting a cut-groove forming step in the wafer dividing method according to the present invention;

[0016] FIG. 5 is a side cross-sectional view depicting a cut-groove rinsing step in the wafer dividing method according to the present invention;

[0017] FIG. 6 is a side cross-sectional view depicting a water-soluble resin filling step in the wafer dividing method according to the present invention;

[0018] FIG. 7 is a side cross-sectional view depicting a protective sheet bonding step in the wafer dividing method according to the present invention;

[0019] FIG. 8 is a side cross-sectional view depicting a second holding step in the wafer dividing method according to the present invention;

[0020] FIG. 9 is a side cross-sectional view depicting a grinding step in the wafer dividing method according to the present invention; and

[0021] FIG. 10 is a side cross-sectional view depicting a water-soluble resin removing step in the wafer dividing method according to the present invention.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENT

[0022] With reference to the attached drawings, a description will be made about an embodiment of the present invention. As depicted in FIG. 1, a wafer W that is to be divided by a dividing method according to the present invention is, for example, a thin disk-shaped member formed of single

crystal silicon (Si), its front surface (an upper surface in FIG. 1) is defined into a plurality of rectangular regions by intersecting streets (scribe lines) L1 and L2 arrayed in a lattice pattern, and devices D such as ICs or LSIs are formed in the individual rectangular regions, respectively. It is to be noted that, as the material of the wafer W, silicon carbide (SiC), glass, ceramics, sapphire, or the like may be used besides silicon (Si).

[0023] The wafer dividing method according to the present invention will hereinafter be described with reference to FIGS. 2 to 11.

[0024] The dividing method according to the present invention for the wafer W is a method, in which the wafer W (see FIG. 1) is divided into a plurality of chips C (see FIG. 11) by sequentially performing 1) a first holding step (step S1), 2) a cut-groove forming step (step S2), 3) a cut-groove rinsing step (step S3), 4) a water-soluble resin filling step (step S4), 5) a protective sheet bonding step (step S5), 6) a second holding step (step S6), 7) a grinding step (step S7), and 8) a water-soluble resin removing step (step S8), in this order as depicted in FIG. 2. These individual steps will hereinafter be described respectively.

1) First Holding Step:

[0025] The first holding step is to hold the wafer W on a holding surface of a disk-shaped first chuck table 1 of a cutting machine as depicted in FIG. 3. It is to be noted that, in FIGS. 3 and 4, a left-right direction is assumed to be an X-axis direction, a direction perpendicular to the drawing sheet is assumed to be a Y-axis direction, and an up-down direction is assumed to be a Z-axis direction.

[0026] Here, a disk-shaped porous member 1A of a porous material is centrally fitted in an upper portion of the first chuck table 1, and an upper surface of this porous member 1A constitutes a holding surface on which the wafer W is held. The porous member 1A is connected to a suction source 2 such as a vacuum pump or an ejector, and on the holding surface as the upper surface of the porous member 1A, the wafer W is placed with the front surface (the surface on which the devices D (see FIG. 1) are formed) directed upward. As the porous member 1A is then evacuated by the suction source 2, a negative pressure occurs in the porous member 1A, so that the wafer W is drawn by the negative pressure and is held under suction on the holding surface of the porous member 1A.

[0027] Further, the first chuck table 1 is horizontally movable in the X-axis direction (a cutting feed direction) by an X-axis moving mechanism 3, and is also horizontally movable in the Y-axis direction (an indexing direction) by an undepicted Y-axis moving mechanism. It is to be noted that the X-axis moving mechanism 3 and the undepicted Y-axis moving mechanism are each constituted by a known ball screw mechanism or the like.

2) Cut-Groove Forming Step:

[0028] The cut-groove forming step is to form lattice-patterned, bottomed cut-grooves Wa by cutting (half-cutting) the front surface of the wafer W, which has been held on the first chuck table 1 of the cutting machine in the first holding step, to a predetermined depth h with a cutting blade 11 disposed on a cutting unit 10 depicted in FIG. 4. In this cut-groove forming step, the depth h of the lattice-patterned, bottomed cut-grooves Wa to be formed in the front surface of the wafer W is set to a value that is a depth to such an extent as not to completely cut apart the wafer W and is smaller than a thickness t of the wafer W ($h < t$). In the wafer W after the cut-grooves Wa have been formed, uncut portions W1 of a thickness ($t-h$) therefore remain, and by these uncut portions W1, the wafer W retains its initial disk shape.

[0029] Here, the cutting blade 11 is a thin, disk-shaped cutting tool, and is attached to a tip of a rotatable spindle 12 arranged along the Y-axis, and the spindle 12 is rotated at a high speed along with the cutting blade 11 by an undepicted spindle motor built in a housing 13 of the cutting unit 10. Further, the cutting unit 10 is supported movably in the Z-axis direction (cut-in direction) by an undepicted Z-axis moving mechanism. It is to be noted that the housing 13 is provided with both ejection nozzles 14 and 15 which eject cutting water toward the cutting blade 11 during cutting

processing, and these ejection nozzles **14** and **15** are both connected to a cutting water supply source **16**. It is to be noted that pure water is suitably used as the cutting water.

[0030] In the front surface of the wafer **W**, the cut-grooves **Wa** of the predetermined depth **h** are therefore formed along the streets **L1**, for example, in one direction (see FIG. **1**) by the cutting (half-cutting) with the cutting blade **11** that is rotating at the high speed. Described specifically, when the first chuck table **1** is moved along with the wafer **W** in the X-axis direction (an arrow direction in FIG. **4**) by the X-axis moving mechanism **3** and is positioned below the cutting unit **10**, the front surface of the wafer **W** is imaged by an undepicted imaging unit arranged in the cutting unit **10**. When an image is captured by the imaging of the front surface of the wafer **W** with the imaging unit, the street **L1** to be cut is detected by pattern matching processing based on the image.

[0031] When the street **L1** of the wafer **W** is detected as mentioned above, the position in the Y-axis direction of the cutting blade **11** of the cutting unit **10** is indexed by the undepicted Y-axis moving mechanism, and the position in the Y-axis direction of the cutting blade **11** is brought into alignment with the street **L1** to be cut.

[0032] With the cutting blade **11** rotationally driven at the high speed, the cutting blade **11** is then lowered from the above-described state by a predetermined cut amount with the Z-axis moving mechanism, and, at the same time, the first chuck table **1** and the wafer **W** held thereon are moved in the X-axis direction by the X-axis moving mechanism **3**. The wafer **W** is therefore cut along the street **L1** by the cutting blade **11**. After such an operation has been performed to all the streets **L1** in the one direction, the first chuck table **1** and the wafer **W** held thereon are rotated by 90° with a rotating mechanism (a motor **9** depicted in FIGS. **5** and **6**), and on the wafer **W**, cutting along the street **L2** (see FIG. **1**) in the other direction orthogonal to the streets **L1**, the cutting of which has been completed, is similarly performed. As a result, the cut-grooves **Wa** of the predetermined depth **h** along the streets **L1** and **L2** are formed in the lattice pattern in the front surface of the wafer **W**.

3) Cut-Groove Rinsing Step:

[0033] The cut-groove rinsing step is to rinse the cut-grooves **Wa** of the predetermined depth **h**, which have been formed in the lattice pattern in the front surface of the wafer **W** in the cut-groove forming step as a preceding step, with rinse water as depicted in FIG. **5**. Here, above the first chuck table **1**, an ejection nozzle **5** connected to a rinse water supply source **4** and an ejection nozzle **7** connected to an air supply source **6** are arranged. Further, the motor **9** is connected as a rotary drive source to a rotating shaft **8** extending vertically downward from a center of the first chuck table **1**. It is to be noted that pure water is suitably used as the rinse water.

[0034] Accordingly, in this cut-groove rinsing step, the first chuck table **1** and the wafer **W** held thereon are rotationally driven at a predetermined speed in the indicated arrow direction about a central axis of the rotating shaft **8** by the motor **9**, and, at the same time, the rinse water supplied from the rinse water supply source **4** is ejected from the ejection nozzle **5** toward the lattice-patterned, bottomed cut-grooves **Wa** formed in the front surface of the wafer **W**, so that each cut groove **Wa** is rinsed with the rinse water. By this rinsing of the cut-grooves **Wa** with the rinse water, cutting debris occurred during the cutting processing of the wafer **W** and stuck in the cut grooves **Wa** is removed. Owing to the ejection of the air, which is supplied from the air supply source **6**, from the ejection nozzle **7** toward the front surface of the wafer **W**, the cutting debris removed from the cut-grooves **Wa** and the rinse water are then blown away and removed.

4) Water-Soluble Resin Filling Step:

[0035] The water-soluble resin filling step is to fill each cut-groove **Wa** of the wafer **W** with a water-soluble resin layer **R** as depicted in FIG. **6** by applying a water-soluble liquid resin **r** to the front surface of the wafer **W** and drying it. It is to be noted that polyvinyl alcohol (PVA), polyvinylpyrrolidone (PVP), or the like is used as the water-soluble liquid resin **r**.

[0036] Accordingly, in the water-soluble resin filling step, the first chuck table **1** and the wafer **W** held thereon are rotationally driven at a predetermined speed in the indicated arrow direction about the central axis of the rotating shaft **8** by the motor **9**, and, at the same time, the water-soluble

liquid resin **r** supplied from a liquid resin supply source **17** to a nozzle **18** is dropped from the nozzle **18** toward a central portion of the upper surface of the wafer **W**. The water-soluble liquid resin **r** dropped to the central portion of the upper surface of the wafer **W** is then caused to spread outward in a radial direction of the wafer **W** by a centrifugal force, so that the lattice-patterned, bottomed cut-grooves **Wa** formed in the front surface of the wafer **W** are filled with the water-soluble resin layers **R**. Further, high-speed rotation of the first chuck table **1** at 2,000 rpm allows the water-soluble liquid resin **r** to dry so that the water-soluble resin layers **R** are formed. Air may be ejected from the ejection nozzle **7** toward the central portion of the upper surface of the wafer **W** in order to accelerate the drying of the water-soluble liquid resin **r**. The water-soluble resin filling step may also be performed by holding the wafer **W** on a table different from the cutting machine instead of the first chuck table **1**. It is to be noted that the water-soluble liquid resin **r** may be filled in the cut-grooves **Wa** by horizontally moving the nozzle **18** and the wafer **W** relative to each other.

5) Protective Sheet Bonding Step:

[0037] The protective sheet bonding step is to form a workset **WS1**, which is depicted in FIG. 7, by bonding a sheet **T1** onto the side of the front surface of the wafer **W** in the cut-grooves **Wa** of which the water-soluble resin layers **R** have been filled in the water-soluble resin filling step as a preceding step.

[0038] The sheet **T1** is therefore bonded on the entirety of the front surface (a lower surface in FIG. 7) of the wafer **W** as depicted in FIG. 7, so that the workset **WS1** is formed. It is to be noted that the sheet **T1** is a self-adhesive sheet provided on a base material thereof with a self-adhesive layer, or a thermal fusion-bonding sheet.

[0039] The workset **WS1** depicted in FIG. 7 and formed as described above will be described regarding cases where it is subjected to the second holding step, grinding step, and water-soluble resin removing step to be mentioned as succeeding steps.

6) Second Holding Step:

[0040] The second holding step is to hold the workset **WS1**, which is depicted in FIG. 7, on a second chuck table **20** of a grinding machine as depicted in FIG. 8. Here, the second chuck table **20** of the grinding machine is a disk-shaped member, and a disk-shaped porous member **20A** of a porous material is fitted in a central upper portion of the second chuck table **20**. Further, an upper surface of the porous member **20A** constitutes a holding surface, and the porous member **20A** is selectively connected to a suction source **23** such as a vacuum pump or an ejector via a communication channel **22** formed centrally through the second chuck table **20** and a rotating shaft **21**.

[0041] Accordingly, in this second holding step, the workset **WS1** is placed on the second chuck table **20**, and the wafer **W** is held under suction on the holding surface of the porous member **20A** of the second chuck table **20** with the back surface thereof directed upward. Described specifically, when the porous member **20A** is evacuated by the suction source **23** with the wafer **W** placed on the holding surface of the porous member **20A** of the second chuck table **20** via the sheet **T1**, a negative pressure occurs in the porous member **20A**, so that the wafer **W** of the workset **W1** is drawn by the negative pressure and is held under suction on the holding surface of the porous member **20A** via the sheet **T1**.

7) Grinding Step:

[0042] The grinding step is, as depicted in FIG. 9, to allow the cut-grooves **Wa** to appear in the back surface of the wafer **W** by grinding, with a plurality of block-shaped grinding stones **33b** of the grinding machine, the back surface (an upper surface in FIG. 9) of the wafer **W** of the workset **WS1** which has been held on the second chuck table **20** of the grinding machine in the second holding step as a preceding step.

[0043] Described specifically, as depicted in FIG. 9, a grinding unit **30** is arranged above the second chuck table **20**, and a grinding wheel **33** is detachably secured to a lower surface of a disk-shaped mount **32** that is connected to a lower end of a rotatable vertical spindle **31** of the grinding

unit **30**. Here, the grinding wheel **33** is constituted by a disk-shaped base **33a**, and the grinding stones **33b** arranged in an annular pattern and secured to a lower surface of the base **33a**.

[0044] Further, the spindle **31** of the grinding unit **30** and the grinding wheel **33** secured to the lower end of the spindle **31** are rotationally driven at a predetermined speed in an arrow direction by an undepicted spindle motor, and is moved up or down by an undepicted Z-axis moving mechanism (lift mechanism) at the same time. Furthermore, a plurality of ejection nozzles **34** is vertically formed in the base **33a** of the grinding wheel **33** on an inner side in a radial direction of the grinding stones **33b**, and these ejection nozzles **34** are connected to a grinding water supply source **37** via a plurality of communication paths **35** formed in the mount **32** and a communication channel **36** formed through an axial center of the spindle **31**. It is to be noted that, as depicted in FIG. **10**, a motor **25** as a rotary drive source is connected to the rotating shaft **21** extending vertically downward from the second chuck table **20**.

[0045] When the second chuck table **20** and the workset WS1 held thereon are rotationally driven at a predetermined speed in an arrow direction of FIG. **9** by the motor **25** depicted in FIG. **10**, and, at the same time, the grinding wheel **33** is moved down by a predetermined amount (a grinding margin) with the undepicted Z-axis moving mechanism (lift mechanism), the wafer W is hence evenly ground at the back surface thereof (the upper surface in FIG. **9**) by the rotating grinding stones **33b**. Here, the grinding margin for the back surface of the wafer W is set to a value that the lattice-patterned, bottomed cut grooves Wa formed in the wafer W are allowed to appear in the back surface of the wafer W, specially to a value that a remaining portion (a portion applied with hatching in FIG. **9**, in other word, the uncut portion depicted in FIG. **4**) W1 other than the cut-grooves Wa of the wafer W is removed in its entirety by the grinding and the thickness of the wafer W after the grinding has a value equal to or smaller than the depth h (see FIG. **4**) of the cut-grooves Wa.

[0046] Further, while the wafer W is being ground at the back surface thereof in this grinding step, grinding water from the grinding water supply source **37** is supplied from the ejection nozzles **34** to contact areas (grinding areas) between the grinding stones **33b** and the wafer W via the communication channel **36** and the communication paths **35**, so that the contact areas (grinding areas) between the grinding stones **33b** and the wafer W are cooled to suppress a rise in temperature, and, at the same time, grinding debris occurred by the grinding is washed away. It is to be noted that pure water is suitably used as the grinding water.

[0047] As a result of the grinding of the back surface of the wafer W in this grinding step, the lattice-patterned, bottomed cut-grooves Wa are therefore allowed to appear in the back surface (the upper surface in FIG. **10**) of the wafer W, whereby the wafer W is divided into the chips C as depicted in FIG. **10**.

8) Water-Soluble Resin Removing Step:

[0048] The water-soluble resin removing step is to remove the water-soluble resin layers R (see FIG. **9**) remaining in the lattice-patterned, bottomed cut-groove Wa of the wafer W in the back surface of which the cut-grooves Wa have been allowed to appear by the grinding in the grinding step as a preceding step. Described specifically with reference to FIG. **10**, in this water-soluble resin removing step, rinse water that is supplied from a rinse water supply source **26** arranged above the second chuck table **20** is ejected toward the central portion of the upper surface of the wafer W from an ejection nozzle **27** while the second chuck table **20** and the workset WS1 held thereon are rotated at a predetermined speed in the indicated arrow direction about an axial center of the shaft **21** by the motor **25**.

[0049] The rinse water ejected from the ejection nozzle **27** to the central portion of the upper surface of the wafer W is then caused to evenly spread toward an outer peripheral portion of the wafer W by a centrifugal force, so that the water-soluble resin layers R (see FIG. **9**) remaining in the cut-grooves Wa of the wafer W are dissolved and removed with the rinse water. The wafer W of which the water-soluble resin layers R have been removed from the cut-grooves Wa is then dried

by ejection of air, which is supplied from an air supply source 28 arranged above the second chuck table 20, from an ejection nozzle 29 to the upper surface (back surface) of the wafer W. It is to be noted that pure water is suitably used as the rinse water. It is also to be noted that the water-soluble resin layers R may be dissolved and removed or dried by moving the ejection nozzles 27 and 29 and the wafer W relative to each other along the cut-grooves Wa.

[0050] As described above, the water-soluble resin layers R remaining in the cut-grooves Wa of the wafer W is dissolved and removed with the rinse water in the water-soluble resin removing step, whereby the wafer W is isolated into the chips C as depicted in FIG. 10.

[0051] According to the dividing method of the present embodiment for the wafer W, it is configured to divide the wafer W into the chips C by forming, in the water-soluble resin filling step, the water-soluble resin layers R in the lattice-patterned, bottomed cut-grooves (half cut-grooves) Wa which have been formed in the front surface (the surface on which the devices D are formed) of the wafer W in the cut-groove forming step, grinding the wafer W at the back surface thereof and allowing the cut-grooves Wa to appear in the grinding step, and in the water-soluble resin removing step, dissolving and removing, with the rinse water, the water-soluble resin layers R filled in the appeared cut-grooves Wa, as described above. A relatively small amount of the water-soluble resin layer R filled in each cut-groove Wa can hence be dissolved and removed in a short time. As a result, the productivity of the chips C can be improved. In addition, as the cut-grooves Wa are filled with the water-soluble resin layers R in the cutting step, sticking of cutting debris to side surfaces of the divided chips C can be avoided.

[0052] Further, sticking of cutting debris to the cut-grooves Wa can also be avoided because the cut-grooves Wa formed in the wafer W in the cut-groove forming step are configured to be rinsed in the cut-groove rinsing step in the present embodiment.

[0053] Furthermore, sticking of abrasive grits or cutting debris to the side surfaces of the divided chips C can also be avoided in the present embodiment because a dried layer of the water-soluble liquid resin r as formed on the front surface of the wafer W in the water-soluble resin filling step is configured to be dissolved and removed with the rinse water in the water-soluble resin removing step.

[0054] The present invention is not limited to the details of the above-described preferred embodiment. The scope of the invention is defined by the appended claims and all changes and modifications as fall within the equivalence of the scope of the claims are therefore to be embraced by the invention.

Claims

1. A method of dividing a wafer, which is defined at a front surface thereof into a plurality of regions by a plurality of intersecting streets and carries devices formed in the regions, respectively, along the streets to obtain a plurality of chips, the method comprising: holding the wafer on a first chuck table of a cutting machine with the front surface directed upward, cutting the front surface of the wafer to a predetermined depth along the streets with a cutting blade of the cutting machine to form bottomed cut-grooves, applying a water-soluble liquid resin from a side of the front surface of the wafer and drying the water-soluble liquid resin to fill the cut-grooves with the resulting dried water-soluble resin, bonding a protective sheet onto the front surface of the wafer, holding the wafer on a second chuck table of a grinding machine with a back surface thereof directed upward, grinding the wafer, which is held on the second chuck table, at the back surface thereof with grinding stones, so that the cut-grooves are allowed to appear in the back surface of the wafer and the wafer is divided into individual chips, and ejecting rinse water against the wafer, which has been divided into the chips, to remove the water-soluble resin filled in the cut-grooves.
